

٠٢٣ / Descriptions

TO-251 N MOS N-CHANNEL MOSFET in a TO-251 Plastic Package.

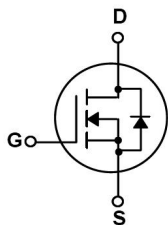
• ٤ / Features

, $R_{DS(on)}$,
Low gate charge, Low ON Resistance, fast switching.

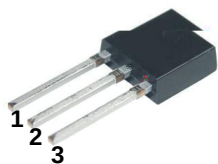
٧ ٤ / Applications

Power switch circuit of adaptor and charger.

٧ ٤ ٤ = ٤ / Equivalent Circuit



٤ ١ ٥ / Pinning



PIN1 G PIN 2 D PIN 3 S

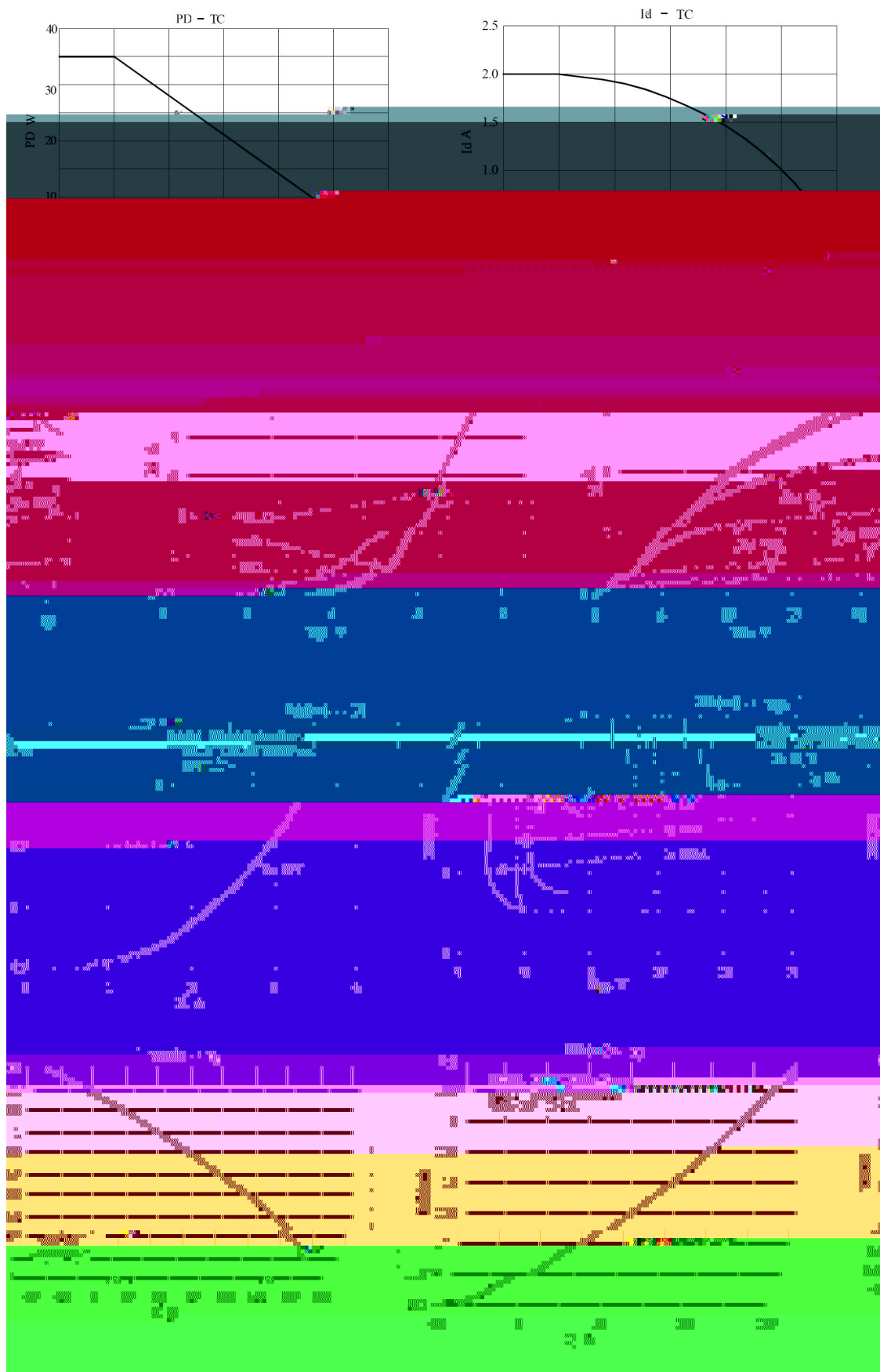
٤. ٨ ٤ / Marking

See Marking Instructions.

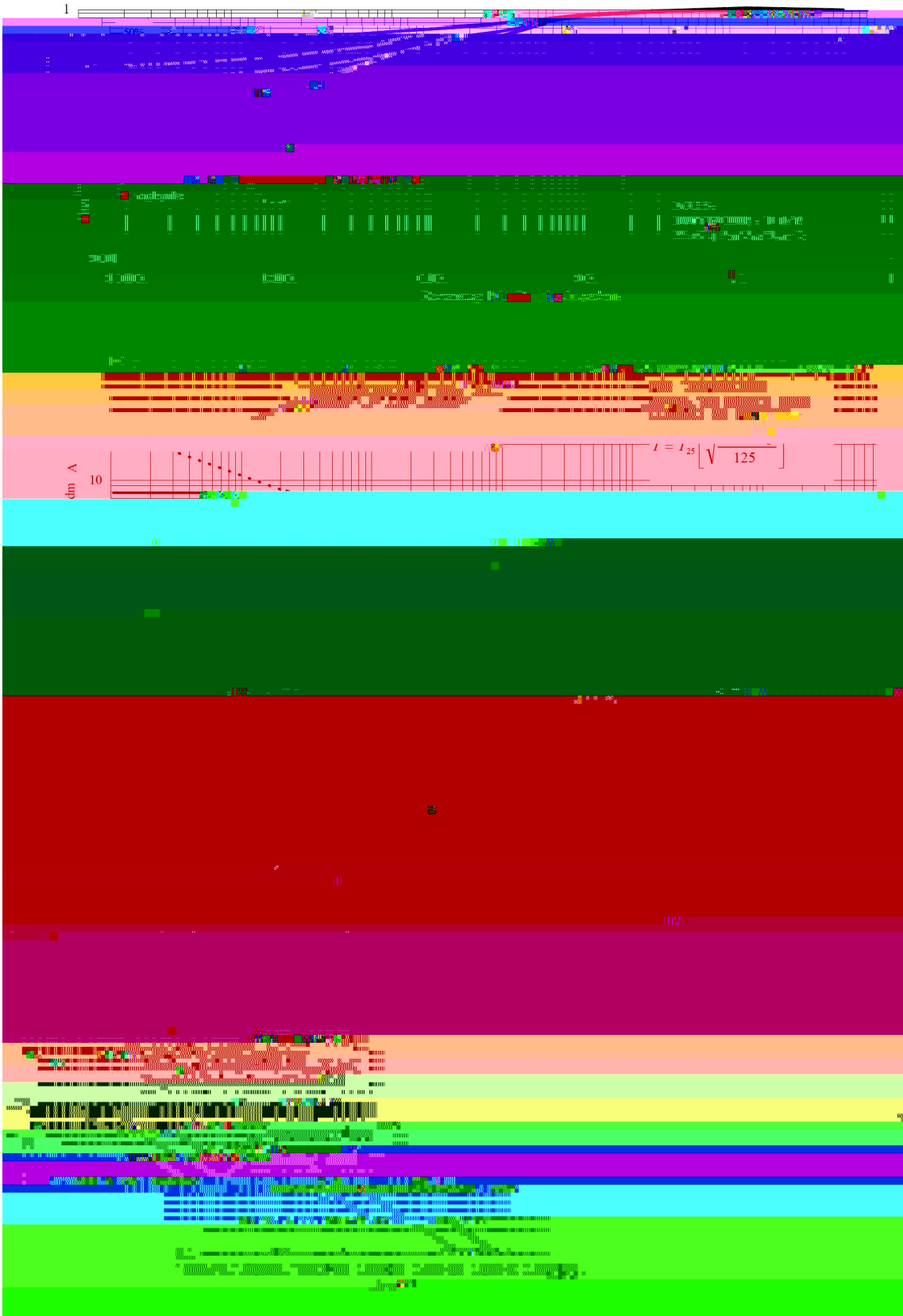
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=350V$ $I_D=2.0A$ $V_{GS}=10V$ $R_G=25\Omega$		7.8		ns
Turn-On Rise Time	t_r			5.5		ns
Turn-Off Delay Time	$t_{d(off)}$			33		ns
Turn-Off Fall Time	t_f			16		ns
Total Gate Charge	Q_g	$I_D=2.0A$ $V_{DD}=350V$ $V_{GS}=10V$		8.5		nC
Gate to Source Charge	Q_{gs}			1.5		nC

Gate to Drain (“ Miller ”)

Electrical Characteristic Curve

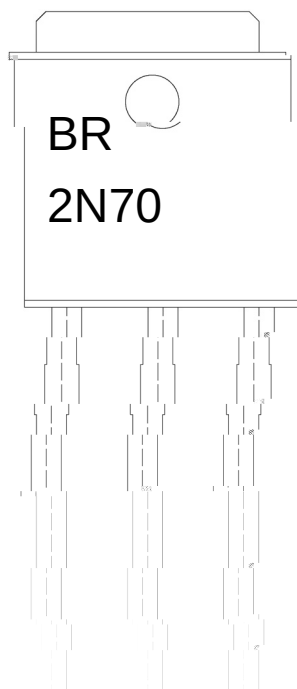


Electrical Characteristic Curve



BRI2N70

4. 1. 1 / Marking Instructions



BR

2N70

Note:

BR: Company Code

2N70: Product Type.

****: Lot No. Code, code change with Lot No.

↓ \$ ¶ ŵ'E Ⅵ f(ŵ'ŝ) / Temperature Profile for Dip Soldering(Pb-Free)



Note:			
1	25 150	60 90sec;	1.Preheating:25~150 , Time:60~90sec.
2	255±5	5±0.5sec;	2.Peak Temp.:255±5 , Duration:5±0.5sec.
3			